

NPN Epitaxial Silicon Transistor

KSD882

Recommended Applications

• Audio Frequency Power Amplifier

Features

- Low Speed Switching
- Complement to KSB772

ABSOLUTE MAXIMUM RATINGS

(T_A = 25°C unless otherwise noted) (Note 1)

Symbol	Parameter	Ratings	Units
BV _{CBO}	Collector-Base Voltage	40	V
BV _{CEO}	Collector-Emitter Voltage	30	V
BV _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	3	Α
I _{CP}	Collector Current (Pulse) (Note 2)	7	Α
I _B	Base Current	0.6	Α
P _D	Total Device Dissipation, $T_C = 25^{\circ}C$ $T_A = 25^{\circ}C$	10 1	W
$T_{J_1}T_{STG}$	Junction and Storage Temperature	-55 ~ +150	

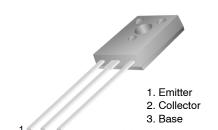
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

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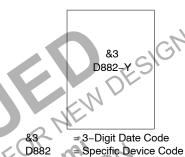
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2. PW ≤ 10 ms, Duty Cycle ≤ 50%.



TO-126-3LD CASE 340AS

MARKING DIAGRAM



= hFE Grade ORDERING INFORMATION

Device	Package	Shipping
KSD882YS	TO-126-3 (Pb-Free)	2000 Units / Bulk Bag
KSD882YSTU	TO-126-3 (Pb-Free)	1920 Units / Tube

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Characteristic	Test Condition	Min	Тур.	Max	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 500 \mu A, I_E = 0$	40	_	_	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 5 \text{ mA}, I_B = 0$	30	_	_	V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 500 \mu A, I_C = 0$	5	-	_	V
I _{CBO}	Collector Cut-off Current	V _{CB} = 30 V, I _E = 0	-	-	1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 3 \text{ V, } I_{C} = 0$	-	-	1	μΑ
h _{FE1} h _{FE2}	DC Current Gain (Note 3)	V _{CE} = 2 V, I _C = 20 mA V _{CE} = 2 V, I _C = 1 A	30 60	150 160	400	
V _{CE} (sat)	Collector–Emitter Saturation Voltage (Note 3)	$I_C = 2 \text{ A}, I_B = 0.2 \text{ A}$	-	0.3	0.5	٧
V _{BE} (sat)	Base-Emitter Saturation Voltage (Note 3)	I _C = 2 A, I _B = 0.2 A	-	1.0	2.0	V
f _T	Current Gain Bandwidth Product	V _{CE} = 5 V, I _E = 0.1 A	_	90	-	MHz
C _{ob}	Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 1 MHz		45	7.5	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

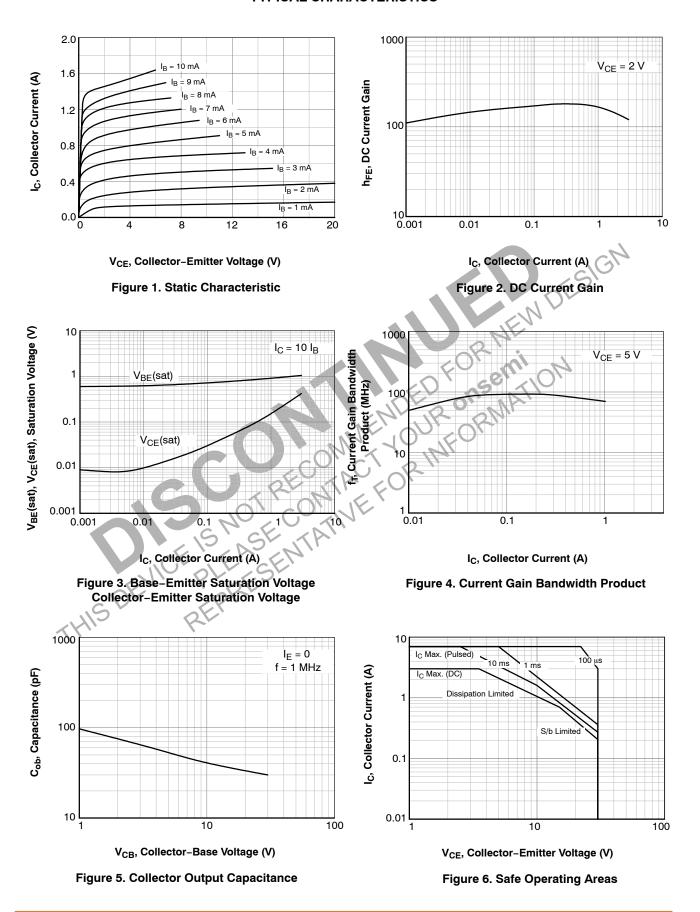
hFE CLASSIFICATION

Classification	R	0	OK- i	G
h _{FE2}	60 ~ 120	100 ~ 200	160 ~ 320	200 ~ 400
			FINE ORINAT	
		-CMD	IR RIVI	
		MILLIC)O,'EO,	
		COMICT	1/M	
		EU DO OF	`	
	GU X	YN FO		
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OE	ICE PLEASE	EMIL		
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THIS DEN	ICE IS EAST REPRES	RECOMMY YOUR CONTACT OF		
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^{3.} Pulse Test: PW ≤ 350 μs, Duty Cycle ≤ 2% Pulsed.

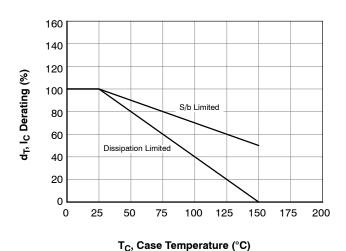
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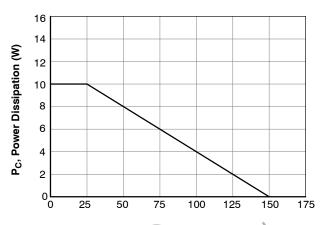
TYPICAL CHARACTERISTICS



KSD882

TYPICAL CHARACTERISTICS (continued)



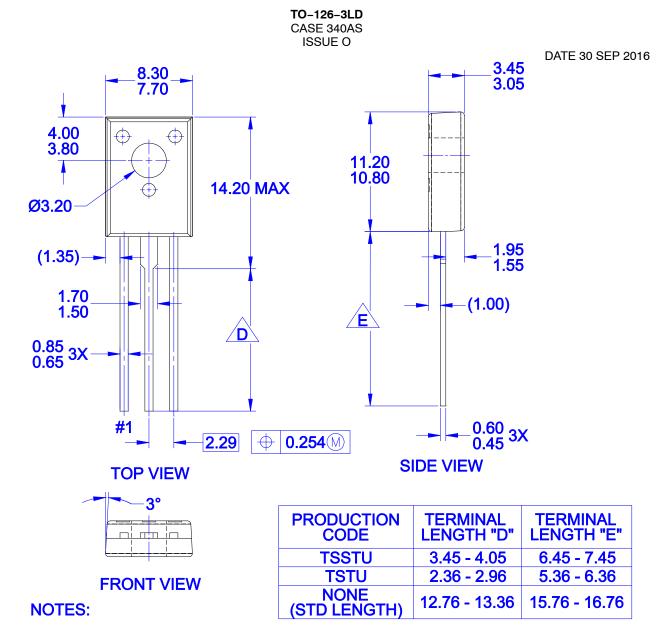


Power E. S. Power E. S. Power E. S. Power E. S. Portage on Sentiton of Recommendation of Recommendatio Figure 7. Derating Curve of Safe Operating

Figure 8. Power Derating

T_C, Case Temperature (°C)





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- B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR PROTRUSIONS

FOR TERMINAL LENGTH "E", REFER TO TABLE



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